

2SK1400, 2SK1400A

Silicon N Channel MOS FET

REJ03G0940-0200
(Previous: ADE-208-1280)
Rev.2.00
Sep 07, 2005

Application

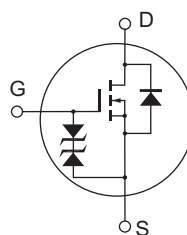
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

Outline

RENESAS Package code: PRSS0004AC-A
(Package name: TO-220AB)



1. Gate
2. Drain
(Flange)
3. Source

Absolute Maximum Ratings

(Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1400	V_{DSS}	300	V
	2SK1400A		350	
Gate to source voltage		V_{GSS}	± 30	V
Drain current		I_D	7	A
Drain peak current		$I_{D(pulse)}^{*1}$	28	A
Body to drain diode reverse drain current		I_{DR}	7	A
Channel dissipation		P_{ch}^{*2}	50	W
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$ 2. Value at $T_C = 25^\circ C$

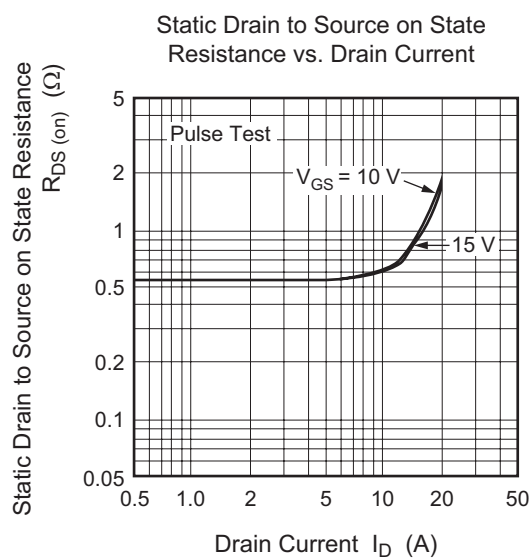
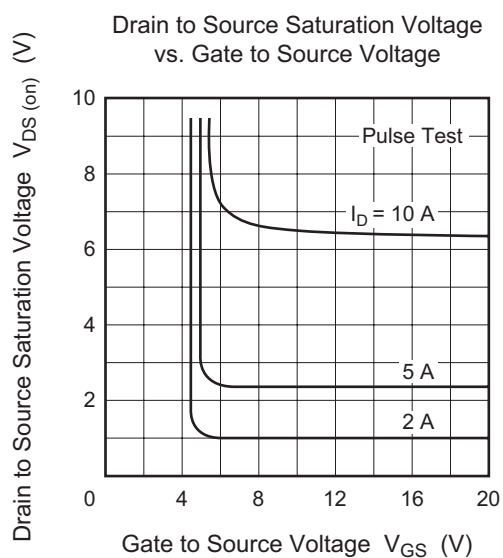
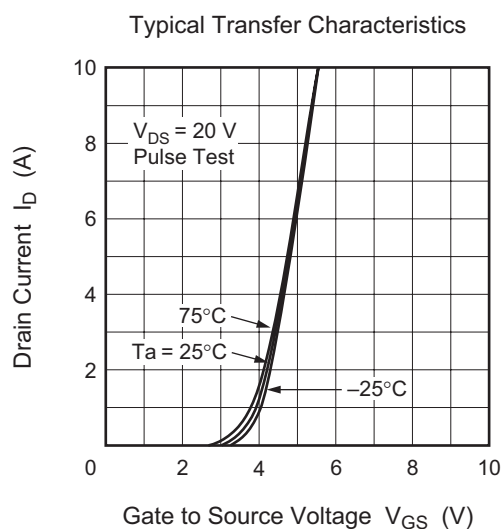
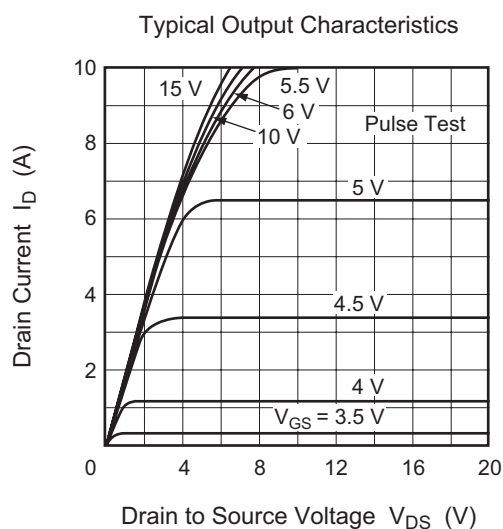
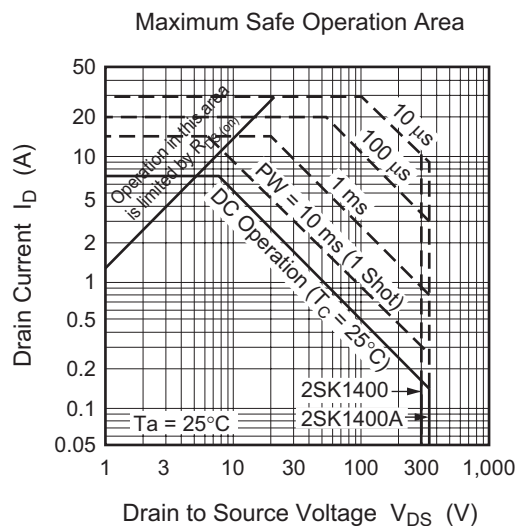
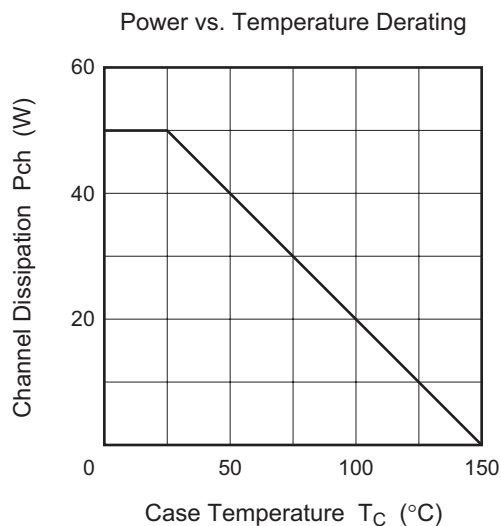
Electrical Characteristics

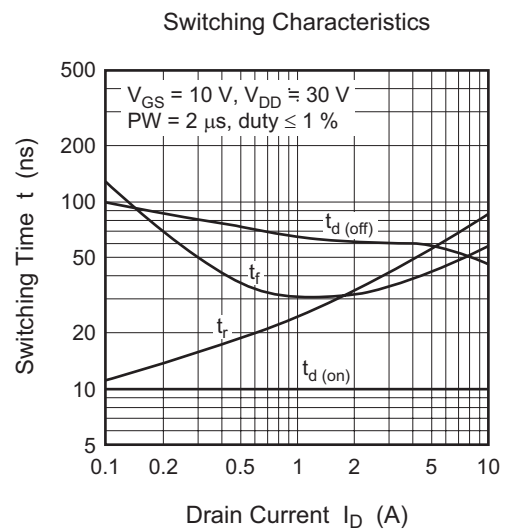
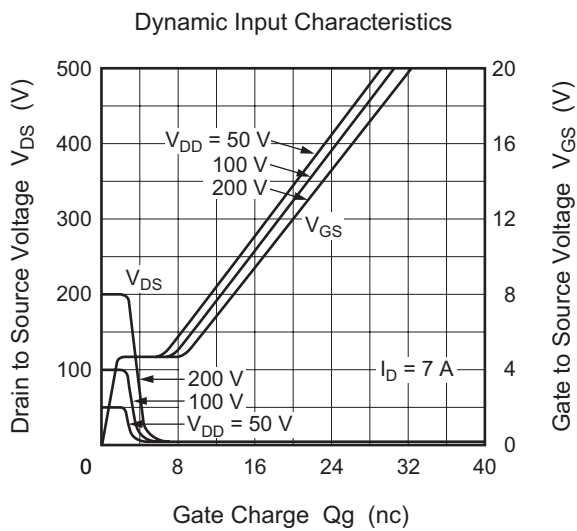
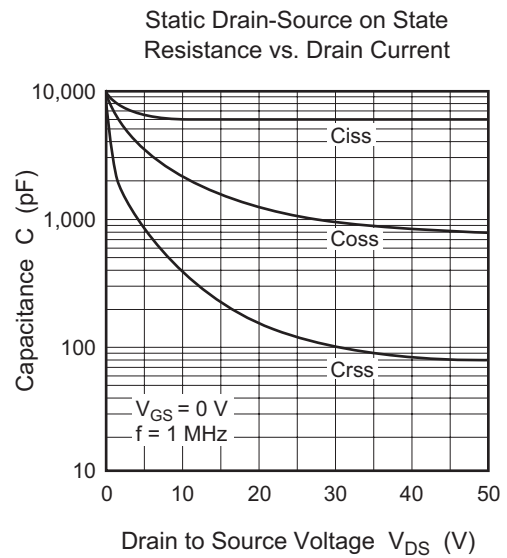
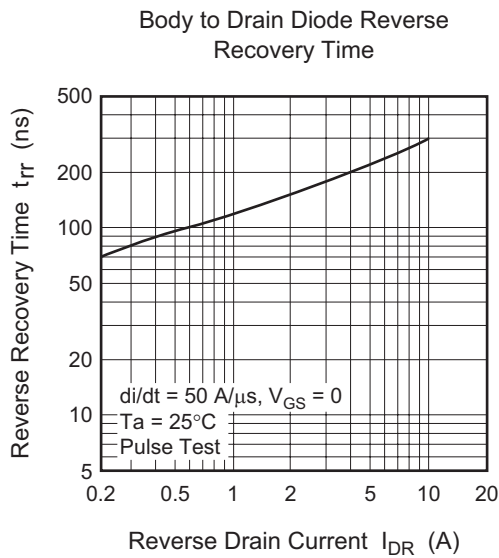
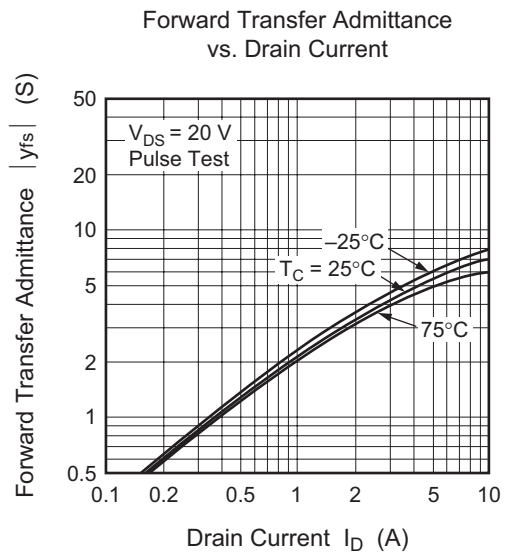
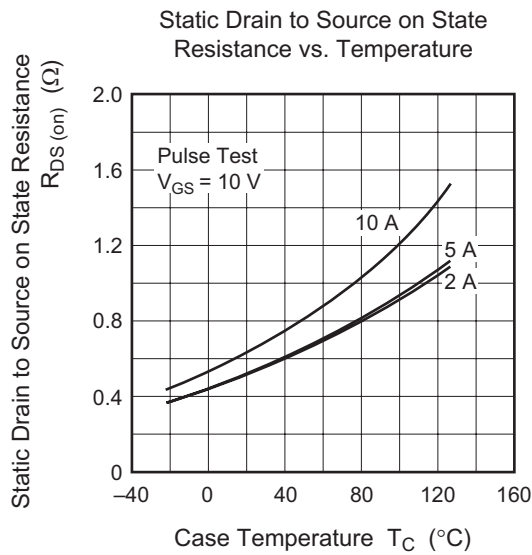
(Ta = 25°C)

Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK1400	$V_{(BR)DSS}$	300	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
	2SK1400A		350	—	—		
Gate to source breakdown voltage		$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100 \mu A$, $V_{DS} = 0$
Gate to source leak current		I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	2SK1400	I_{DSS}	—	—	250	μA	$V_{DS} = 240 \text{ V}$, $V_{GS} = 0$
	2SK1400A						$V_{DS} = 280 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage		$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	2SK1400	$R_{DS(on)}$	—	0.50	0.70	Ω	$I_D = 4 \text{ A}$, $V_{GS} = 10 \text{ V}^{*3}$
	2SK1400A		—	0.60	0.80		
Forward transfer admittance		$ y_{fs} $	3.0	5.0	—	S	$I_D = 4 \text{ A}$, $V_{DS} = 10 \text{ V}^{*3}$
Input capacitance		C_{iss}	—	635	—	pF	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance		C_{oss}	—	230	—	pF	
Reverse transfer capacitance		C_{rss}	—	40	—	pF	
Turn-on delay time		$t_{d(on)}$	—	10	—	ns	$I_D = 4 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_L = 7.5 \Omega$
Rise time		t_r	—	50	—	ns	
Turn-off delay time		$t_{d(off)}$	—	60	—	ns	
Fall time		t_f	—	40	—	ns	
Body to drain diode forward voltage		V_{DF}	—	1.0	—	V	$I_F = 7 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time		t_{rr}	—	240	—	ns	$I_F = 7 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 100 \text{ A}/\mu s$

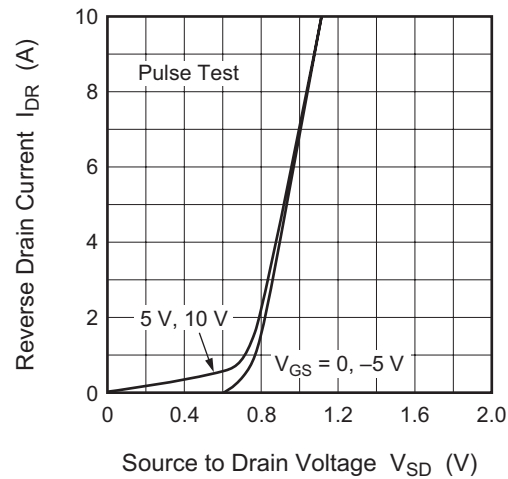
Note: 3. Pulse test

Main Characteristics

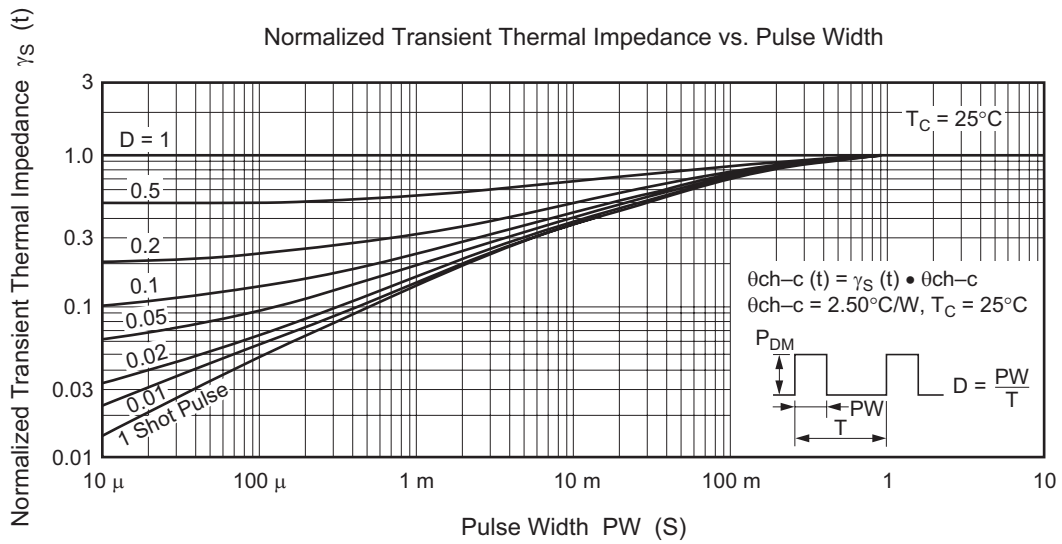




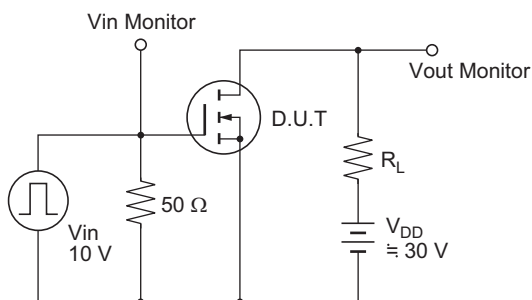
Reverse Drain Current vs.
Source to Drain Voltage



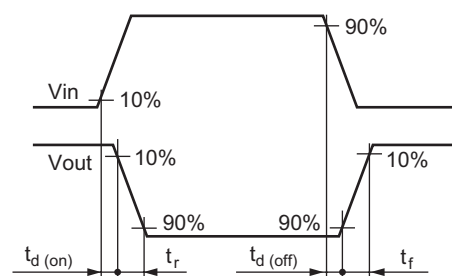
Normalized Transient Thermal Impedance vs. Pulse Width



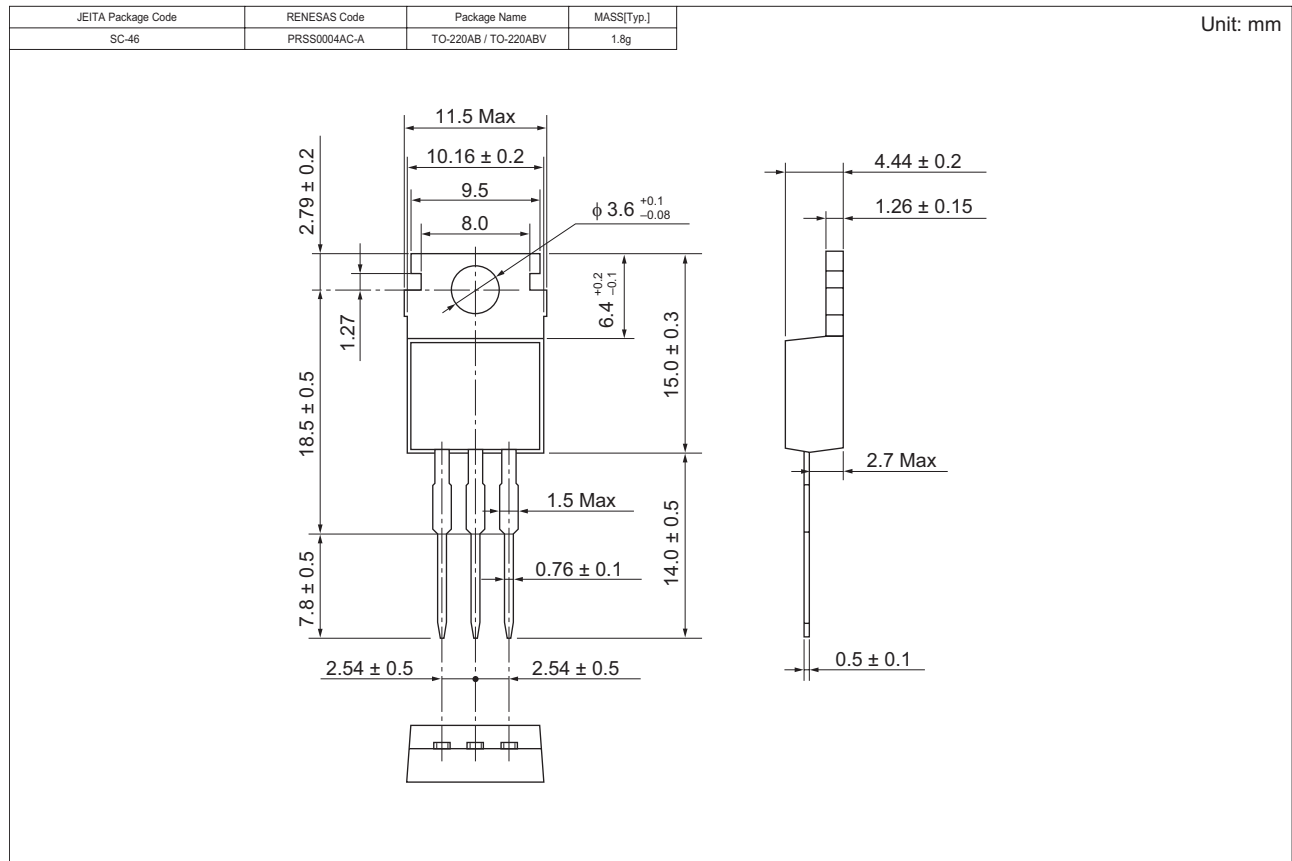
Switching Time Test Circuit



Waveforms



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK1400-E	500 pcs	Box (Sack)
2SK1400A-E	500 pcs	Box (Sack)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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